

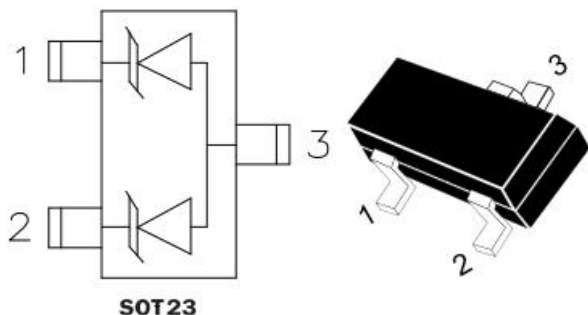
Description

The SOTXXC is an uni-directional TVS diode array, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting sensitive semiconductor components from damage. The SOTXXC complies with the IEC 61000-4-2 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a lead-free SOT-23 package. It is designed to protect components which are connected to data and transmission lines from voltage surges.

Features

- 350W peak pulse power (8/20us)
- Protects one bi-directional or two uni-directional line(s)
- Ultra low leakage: nA level
- Stand-off Voltage: 3.3 V ~ 36 V
- Ultra low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
- RoHS Compliant

Dimensions & Symbol (Unit: mm Max)



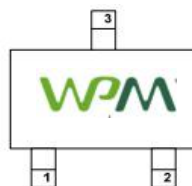
Mechanical Characteristics

- Package: SOT-23
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Set Top Box
- Industrial Controls
- Server and Desktop PC

Marking information



Details marking code reference customer approval list

Ordering Information

Part Number	Packaging	Reel Size
SOT03C	3000/Tape & Reel	7 inch
SOT05C	3000/Tape & Reel	7 inch
SOT12C	3000/Tape & Reel	7 inch
SOT15C	3000/Tape & Reel	7 inch
SOT24C	3000/Tape & Reel	7 inch
SOT36C	3000/Tape & Reel	7 inch

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

SOT03C			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	350	W
Peak Pulse Current (8/20μs)	Ipp	25	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
SOT05C			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	350	W
Peak Pulse Current (8/20μs)	Ipp	23	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
SOT12C			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	350	W
Peak Pulse Current (8/20μs)	Ipp	12	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

SOT15C			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	350	W
Peak Pulse Current (8/20μs)	Ipp	10	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
SOT24C			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	350	W
Peak Pulse Current (8/20μs)	Ipp	6	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
SOT36C			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	350	W
Peak Pulse Current (8/20μs)	Ipp	4	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

SOT03C						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			3.3	V	
Breakdown Voltage	VBR	4.0			V	IT = 1mA
Reverse Leakage Current	IR			1	uA	VRWM = 3.3V
Clamping Voltage	VC		7.5		V	IPP = 1A (8 x 20uS pulse)
Clamping Voltage	VC			15	V	IPP = 25A (8 x 20uS pulse)
Junction Capacitance	CJ			240	pF	VR = 0V, f = 1MHz

SOT05C						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6.0			V	IT = 1mA
Reverse Leakage Current	IR			1		VRWM = 5V
Clamping Voltage	VC			8	V	IPP = 1A (8 x 20uS pulse)
Clamping Voltage	VC			14	V	IPP = 23A (8 x 20uS pulse)
Junction Capacitance	CJ		160		pF	VR = 0V, f = 1MHz

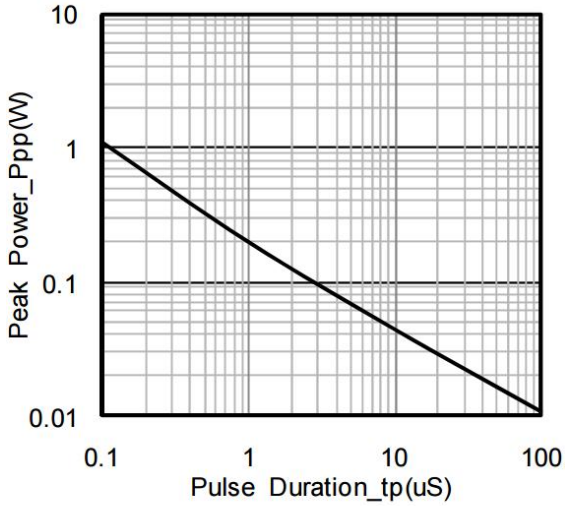
SOT12C						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			12	V	
Breakdown Voltage	VBR	13.3			V	IT = 1mA
Reverse Leakage Current	IR			1	uA	VRWM = 12V
Clamping Voltage	VC			16	V	IPP = 1A (8 x 20uS pulse)
Clamping Voltage	VC			30	V	IPP = 12A (8 x 20uS pulse)
Junction Capacitance	CJ			90	pF	VR = 0V, f = 1MHz

SOT15C						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			15	V	
Breakdown Voltage	VBR	16.7			V	IT = 1mA
Reverse Leakage Current	IR			1	uA	VRWM =15V
Clamping Voltage	VC		24		V	IPP = 1A (8 x 20uS pulse)
Clamping Voltage	VC			35	V	IPP = 10A (8 x 20uS pulse)
Junction Capacitance	CJ			55	pF	VR = 0V, f = 1MHz

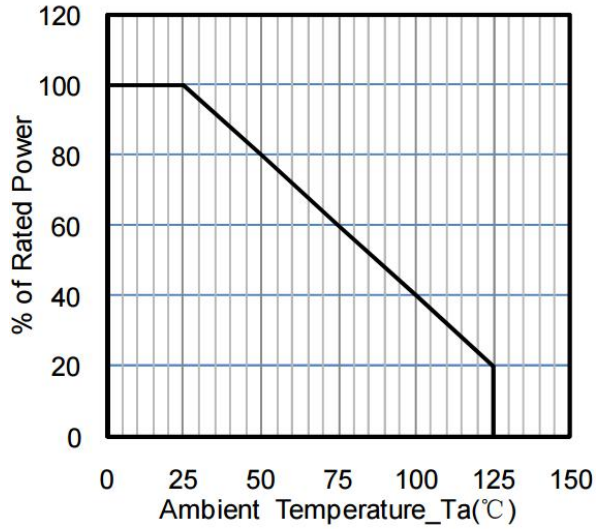
SOT24C						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			24	V	
Breakdown Voltage	VBR	26.7			V	IT = 1mA
Reverse Leakage Current	IR			1	uA	VRWM =24V
Clamping Voltage	VC		35		V	IPP = 1A (8 x 20uS pulse)
Clamping Voltage	VC			55	V	IPP = 6A (8 x 20uS pulse)
Junction Capacitance	CJ			40	pF	VR = 0V, f = 1MHz

SOT36C						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			36	V	
Breakdown Voltage	VBR	40			V	IT = 1mA
Reverse Leakage Current	IR			1	uA	VRWM =36V
Clamping Voltage	VC		55		V	IPP = 1A (8 x 20uS pulse)
Clamping Voltage	VC			75	V	IPP = 4A (8 x 20uS pulse)
Junction Capacitance	CJ			35	pF	VR = 0V, f = 1MHz

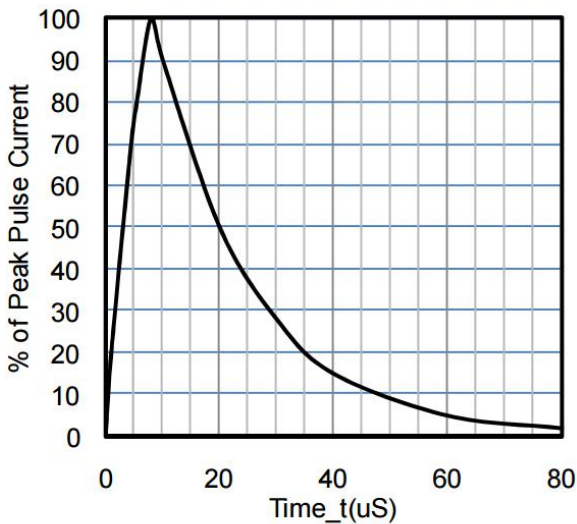
Typical Performance Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise Specified)



Peak Pulse Power vs. Pulse Time



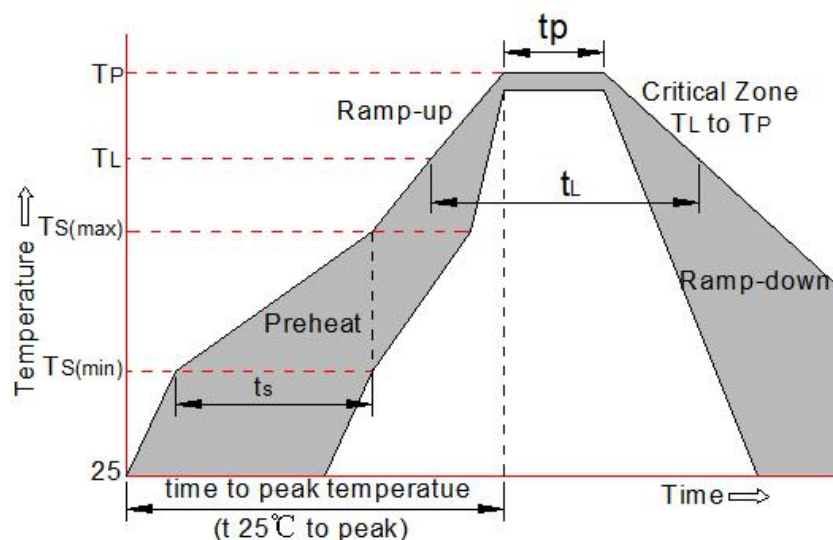
Power Derating Curve



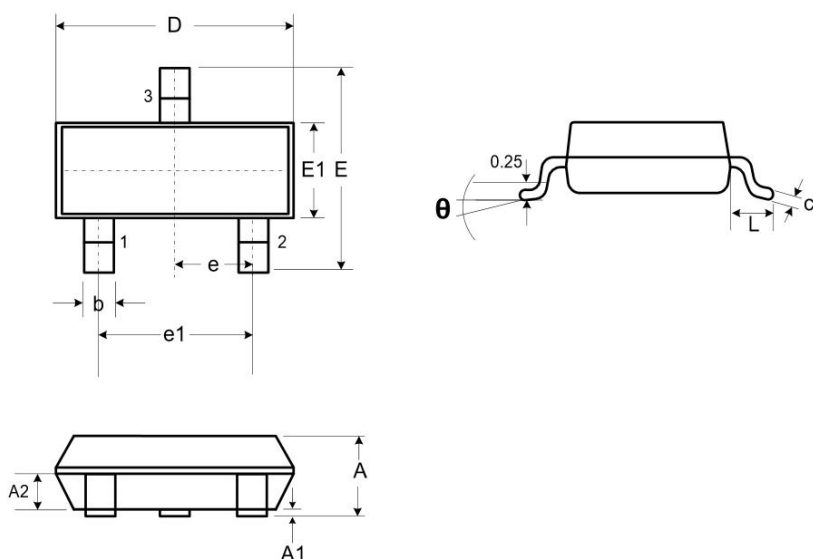
8 X 20uS Pulse Waveform

Soldering parameters

Reflow Condition		Pb-Free assembly (see FIG.2)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (t_s)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L) (Liquid us)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T_p)		8 min. Max
Do not exceed		+260°C

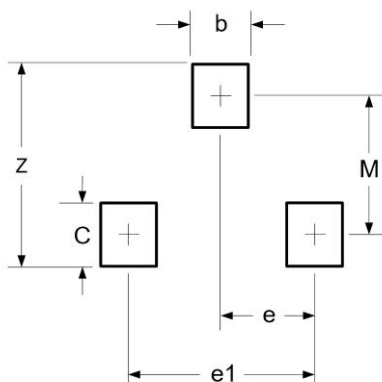


Package mechanical data



DIMENSIONS				
SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.90	1.15	0.035	0.045
A1	0.00	0.10	0.000	0.004
A2	0.60	0.70	0.0236	0.0275
b	0.30	0.50	0.012	0.020
c	0.08	0.15	0.003	0.006
D	2.80	3.00	0.110	0.118
E	2.25	2.55	0.089	0.100
E1	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 BSC	
e1	1.80	2.00	0.071	0.079
L	0.30	0.50	0.012	0.020
θ	0	8°	0	8°

Suggested Land Pattern



DIMENSIONS		
DIM	INCHES	MILLIMETERS
M	0.0795	2.02
C	0.0315	0.80
Z	0.111	2.82
e	0.037 BSC	0.95 BSC
e1	0.075 BSC	1.9 BSC
b	0.0315	0.80

Contact information

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